Unit: mm

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

# **2SJ148**

## High Speed Switching Applications Analog Switch Applications Interface Applications

- Excellent switching time: ton = 14 ns (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 100 \text{ mS (min)}$
- Low on resistance: RDS (ON) =  $1.3 \Omega$  (typ.)
- Enhancement-mode
- Complementary to 2SK982

### Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V <sub>DSS</sub>	-60	V	
Gate-source voltage		V <sub>GSS</sub>	±20	V	
Drain current	DC	I <sub>D</sub>	-200	mA	
	Pulse	I <sub>DP</sub>	-800		
Drain power dissipation (Ta = 25°C)		P <sub>D</sub>	400	mW	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

1. SOURCE 2. DRAIN 3. GATE

JEDEC TO-92

JEITA SC-43

TOSHIBA 2-5F1H

Weight: 0.21 g (typ.)

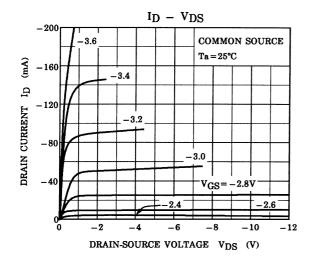


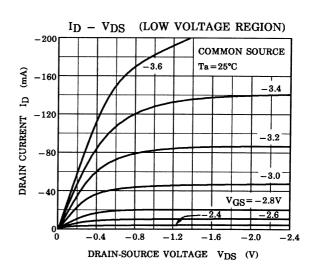
## Electrical Characteristics (Ta = 25°C)

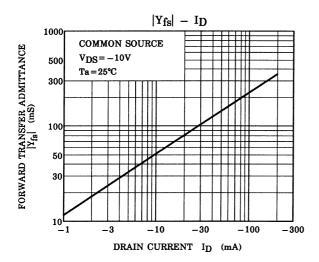
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I <sub>GSS</sub>	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$	_	_	±100	nA
Drain cut-off curre	ent	I <sub>DSS</sub>	$V_{DS} = -60 \text{ V}, V_{GS} = 0$	_	_	-10	μΑ
Drain-source brea	akdown voltage	V (BR) DSS	$I_D = -1 \text{ mA}, V_{GS} = 0$	-60	_	_	V
Gate threshold vo	oltage	V <sub>th</sub>	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$	-2	_	-3.5	٧
Forward transfer	admittance	Y <sub>fs</sub>	$V_{DS} = -10 \text{ V}, I_D = -50 \text{ mA}$	100	_	_	mS
Drain-source ON	resistance	R <sub>DS</sub> (ON)	$I_D = -50 \text{ mA}, V_{GS} = -10 \text{ V}$		1.3	2.0	Ω
Drain-source ON	voltage	V <sub>DS</sub> (ON)	$I_D = -50 \text{ mA}, V_{GS} = -10 \text{ V}$		-65	-100	mV
Input capacitance	•	C <sub>iss</sub>	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0, f = 1 MHz		73	85	pF
Reverse transfer capacitance		C <sub>rss</sub>	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0, f = 1 MHz		15	22	pF
Output capacitance		C <sub>oss</sub>	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0, f = 1 MHz		48	60	pF
Switching time	Rise time	t <sub>r</sub>	10 I <sub>D</sub> = -100mA -10V V <sub>IN</sub> V <sub>OUT</sub> V <sub>OUT</sub> V <sub>OUT</sub>	_	8	_	ns
	Turn-on time	t <sub>on</sub>		_	14	_	
	Fall time	t <sub>f</sub>	$\psi_{\rm re}$ $\Lambda^{\rm DD} = -30 \Lambda_{\rm p}$	_	35	_	
	Turn-off Time	t <sub>off</sub>	$\begin{aligned} & V_{\text{IN}} \colon t_r,  t_f < 5 \text{ ns} \\ & \text{D.U.} \le 1\% \; (Z_{\text{out}} = 50 \; \Omega) \end{aligned}$		100		

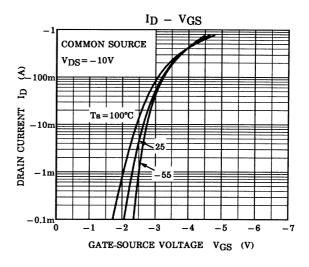
This transistor is the electrostatic sensitive device. Please handle with caution.

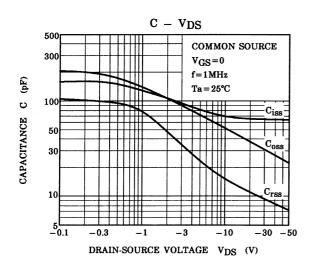
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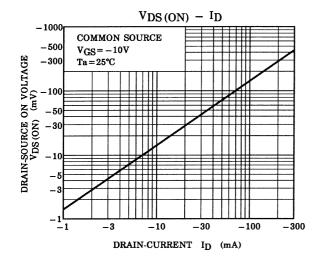


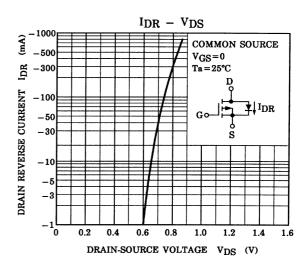


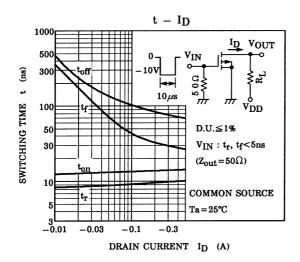


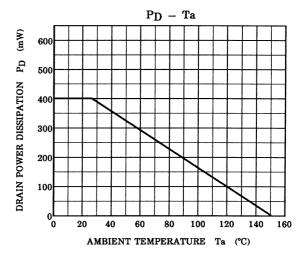


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